

# SANYO Semiconductors DATA SHEET



## **Bi-CMOS LSI** LV8741V — PWM Constant-Current Control **Stepping Motor Driver**

### **Overview**

The LV8741V is a PWM current-control stepping motor driver IC.

### Features

- Single-channel PWM current control stepping motor driver (selectable with DC motor driver channel 2) incorporated.
- BiCDMOS process IC
- On resistance (upper side :  $0.5\Omega$ ; lower side :  $0.5\Omega$ ; total of upper and lower :  $1.0\Omega$ ; Ta = 25°C, I<sub>O</sub> = 1.5A)
- Excitation mode can be set to 2-phase, 1-2 phase full torque, 1-2 phase or W1-2 phase
- Excitation step proceeds only by step signal input
- Motor holding current selectable in four steps
- IO max = 1.5A
- Output-stage push-pull structure enabling high-speed operation
- Output short-circuit protection circuit (selectable from latch-type or auto reset-type) incorporated
- Thermal shutdown circuit and power supply monitor circuit incorporated
- Supports control power supply  $V_{CC} = 3.3V$

### **Specifications**

### Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage 1	V <sub>M</sub> max		38	V
Supply voltage 2	V <sub>CC</sub> max		6	V
Output peak current	I <sub>O</sub> peak	tw $\leq$ 10ms, duty 20%	1.75	А
Output current	I <sub>O</sub> max		1.5	А
Logic input voltage	VIN		-0.3 to V <sub>CC</sub> +0.3	V
EMO input voltage	VEMO		-0.3 to V <sub>CC</sub> +0.3	V

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Parameter	Symbol	Conditions	Ratings	Unit
Allowable power dissipation 1	Pd max1	Independent IC	0.55	W
Allowable power dissipation 2	Pd max2	* Our recommended two-layer substrate *1, *2	2.9	W
Operating temperature	Topr		-20 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

\*1 Specified circuit board : 90×90×1.7mm^3 : glass epoxy printed circuit board

 $^{\ast}2$  For mounting to the backside by soldering, refer the precautions.

### Recommended Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage range 1	VM		9.5 to 35	V
Supply voltage range 2	V <sub>CC</sub>		2.7 to 5.5	V
VREF input voltage range	VREF		0 to V <sub>CC</sub> -1.8	V

### **Electrical Characteristics** at $Ta = 25^{\circ}C$ , $V_M = 24V$ , $V_{CC} = 5V$ , VREF = 1.5V

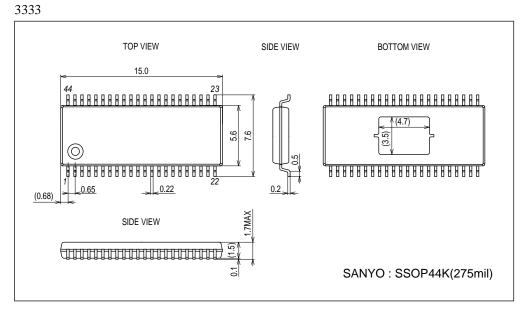
Par	ameter	Symbol	Conditions		Ratings		Unit
		Gymbol	Conditions	min	typ	max	0
Standby mode current drain 1		IMstn	ST = "L"		150	200	μΑ
Current drain 1		IM	ST = "H", OE = "H", no load		0.75	1	mA
Standby mode of	current drain 2	I <sub>CC</sub> stn	ST = "L"		110	160	μΑ
Current drain 2		ICC	ST = "H", OE = "H", no load		2.5	3	mA
V <sub>CC</sub> low-voltage	e cutoff voltage	VthV <sub>CC</sub>		2.2	2.35	2.5	V
Low-voltage hys	steresis voltage	VthHIS		100	150	200	mV
Thermal shutdo	wn temperature	TSD	Design guarantee		180		°C
Thermal hystere	esis width	$\Delta TSD$	Design guarantee		40		°C
Output on-resist	tance	Ronu	$I_{O}$ = 1.5A, Upper-side on resistance		0.5	0.8	Ω
		Rond	$I_{O}$ = 1.5A, Lower-side on resistance		0.5	0.8	Ω
Output leakage	current	lOleak				50	μA
Diode forward v	oltage 1	VD1	ID = -1.0A		1	1.3	V
Diode forward v	oltage 2	VD2	ID = -1.5A		1.1	1.5	V
Logic pin input c	current	IINL	V <sub>IN</sub> = 0.8V	3	8	15	μΑ
		I <sub>IN</sub> H	V <sub>IN</sub> = 5V	30	50	70	μΑ
Logic high-level input voltage		VINH		2.0			V
Logic low-level i	nput voltage	VINL				0.8	V
Current	W1-2-phase		Step 0(When initialized : channel 1	0.485	0.5	0.515	V
selection	drive		comparator level)				
reference			Step 1 (Initial state+1)	0.485	0.5	0.515	V
voltage level			Step 2 (Initial state+2)	0.323	0.333	0.343	V
			Step 3 (Initial state+3)	0.155	0.167	0.179	V
	1-2 phase drive		Step 0 (When initialized: channel 1 comparator level)	0.485	0.5	0.515	V
			Step 2 (Initial state+1)	0.323	0.333	0.343	V
	1-2 phase (full torque) drive		Step 0 (Initial state, channel 1 comparator level)	0.485	0.5	0.515	V
			Step 2 (Initial state+1)	0.485	0.5	0.515	V
	2 phase drive		Step 2	0.485	0.5	0.515	V
Chopping freque	ency	Fchop	RCHOP = 20kΩ	45	62.5	75	kHz
Current setting r	reference voltage	VRF00	ATT1 = L, ATT2 = L	0.485	0.5	0.515	V
		VRF01	ATT1 = H, ATT2 = L	0.323	0.333	0.343	V
		VRF10	ATT1 = L, ATT2 = H	0.237	0.25	0.263	V
		VRF11	ATT1 = H, ATT2 = H	0.155	0.167	0.179	V
VREF pin input	current	Iref	VREF = 1.5V	-0.5			μA

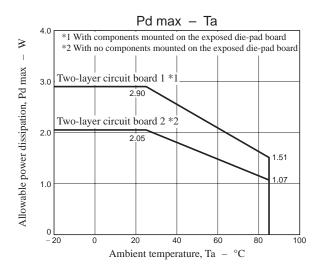
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Parameter	Symbol	Conditions	Ratings			Unit	
	Symbol		min	typ	max	Unit	
Charge pump							
VREG5 output voltage	Vreg5	I <sub>O</sub> = -1mA	4.5	5	5.5	V	
VG output voltage	VG		28	28.7	29.8	V	
Rise time	tONG	VG = 1µF		5	10	ms	
Oscillator frequency	Fosc	$RCHOP = 20 \mathrm{k}\Omega$	90	125	150	kHz	
Output short-circuit protection							
EMO pin saturation voltage		lemo = 1mA		50	100	mV	

### Package Dimensions

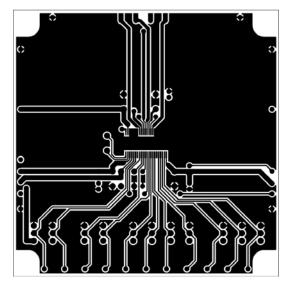
unit : mm (typ)



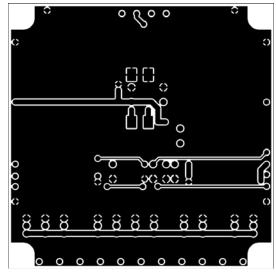


Substrate Specifications (Substrate recommended for operation of LV8741V)

Size	: $90$ mm × $90$ mm × $1.7$ mm (two-layer substrate [2S0P])
Material	: Glass epoxy
Copper wiring density	: $L1 = 90\% / L2 = 95\%$



L1 : Copper wiring pattern diagram



L2 : Copper wiring pattern diagram

### Cautions

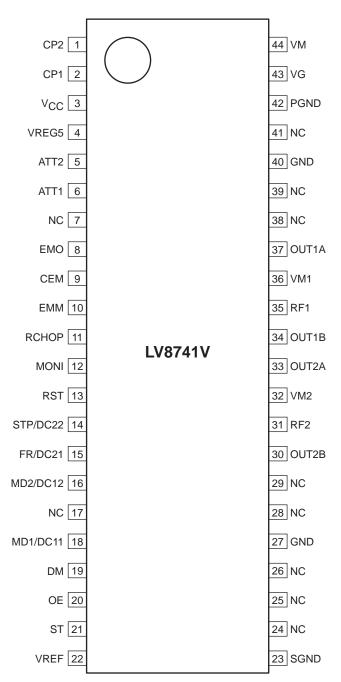
1) The data for the case with the Exposed Die-Pad substrate mounted shows the values when 95% or more of the Exposed Die-Pad is wet.

2) For the set design, employ the derating design with sufficient margin.

Stresses to be derated include the voltage, current, junction temperature, power loss, and mechanical stresses such as vibration, impact, and tension.

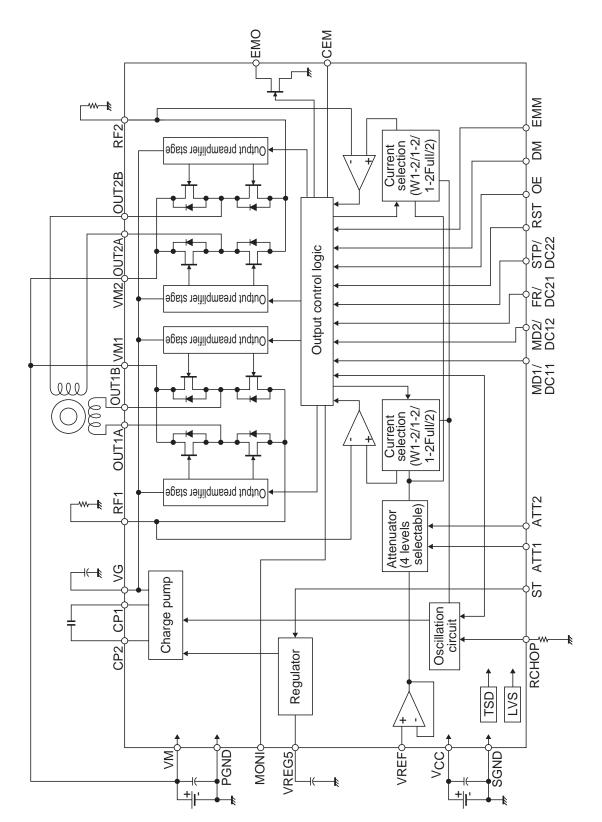
- Accordingly, the design must ensure these stresses to be as low or small as possible.
- The guideline for ordinary derating is shown below :
- (1)Maximum value 80% or less for the voltage rating
- (2)Maximum value 80% or less for the current rating
- (3)Maximum value 80% or less for the temperature rating

3) After the set design, be sure to verify the design with the actual product. Confirm the solder joint state and verify also the reliability of solder joint for the Exposed Die-Pad, etc. Any void or deterioration, if observed in the solder joint of these parts, causes deteriorated thermal conduction, possibly resulting in thermal destruction of IC. **Pin Assignment** 



Top view

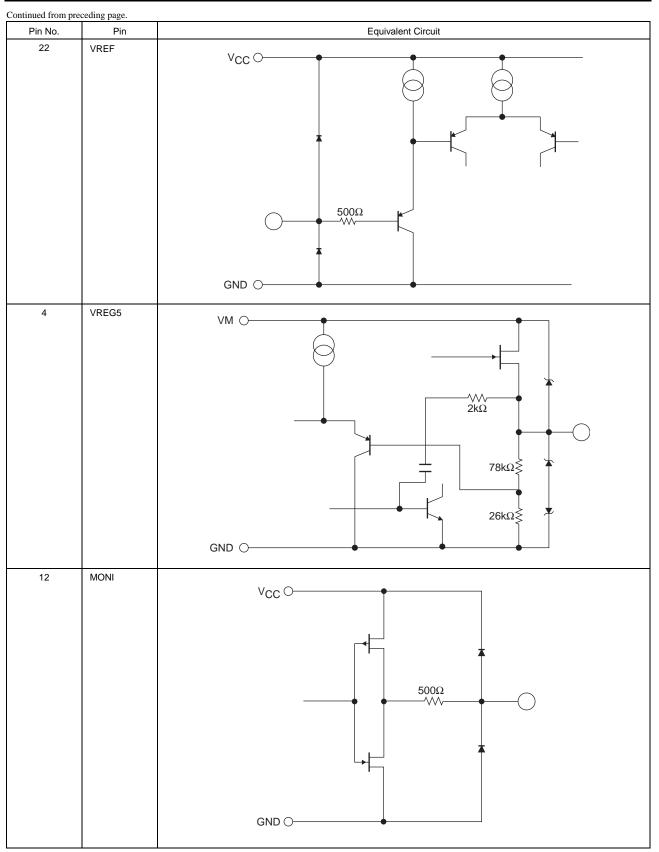
**Block Diagram** 



Pin Functio	ons				
Pin No.	Pin name	Description			
36	VM1	Channel 1 motor power supply pin			
37	OUT1A	nannel 1 OUTA output pin			
34	OUT1B	Channel 1 OUTB output pin			
35	RF1	Channel 1 current-sense resistor connection pin			
32	VM2	Channel 2 motor power supply connection pin			
33	OUT2A	Channel 2 OUTA output pin			
30	OUT2B	Channel 2 OUTB output pin			
31	RF2	Channel 2 current-sense resistor connection pin			
42	PGND	Power system ground			
12	MONI	Position detection monitor pin			
14	STP/DC22	STM STEP signal input pin/DCM2 output control input pin			
22	VREF	Constant current control reference voltage input pin			
18	MD1/DC11	STM excitation mode switching pin/DCM1 output control input pin			
16	MD2/DC12	STM excitation mode switching pin/DCM1 output control input pin			
13	RST	Reset signal input pin			
20	OE	Output enable signal input pin			
15	FR/DC21	STM forward/reverse rotation signal input pin/DCM2 output control input pin			
6	ATT1	Motor holding current switching pin			
5	ATT2	Motor holding current switching pin			
21	ST	Chip enable pin			
44	VM	Motor power supply connection pin			
3	VCC	Logic power supply connection pin			
23	SGND	Signal system ground			
11	RCHOP	Chopping frequency setting resistor connection pin			
19	DM	Drive mode (STM/DCM) switching pin			
4	VREG5	Internal power supply capacitor connection pin			
2	CP1	Charge pump capacitor connection pin			
1	CP2	Charge pump capacitor connection pin			
43	VG	Charge pump capacitor connection pin			
8	EMO	Output short-circuit state warning output pin			
10	EMM	Overcurrent mode switching pin			
9	CEM	Pin to connect the output short-circuit state detection time setting capacitor			
27,40	GND	Ground			
7, 17, 24, 25, 26, 28,	NC	No Connection (No internal connection to the IC)			
29, 38, 39, 41					

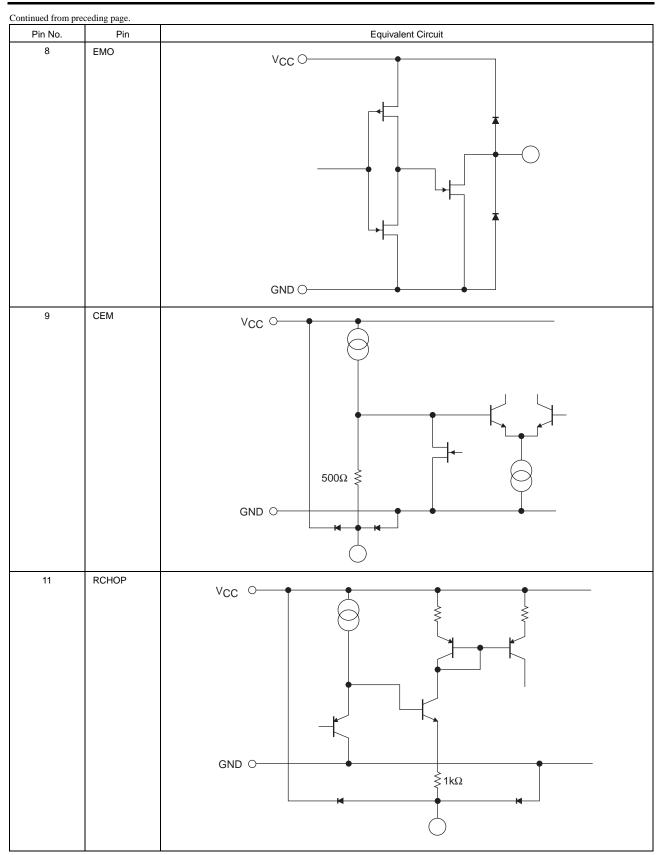
Equivalent	Circuits	
Pin No.	Pin	Equivalent Circuit
5	ATT2	Vac
6	ATT1	Vcc O
10	EMM	
13	RST	
14	STP/DC22	
15	FR/DC21	
16	MD2/DC12	
18	MD1/DC11	
19	DM	5kΩ
20	OE	
21	ST	
		τ ξ100kΩ τ Γ
30	OUT2B	
31	RF2	(36)
32	VM2	32
33	OUT2A	
34	OUT1B	
35	RF1	
36	VM1	
37	OUT1A	
42	PGND	
		3733
		GND O
		$\bigcirc$ $\bigcirc$
1	CP2	
2	CP1	(2) (44) (1) (43)
43	VG	
44	VM	│ ┌ <del>⋗</del> ┥ ┌ <del>⋗</del> ┥ ┌ <del>⋗</del> ┥
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LV8741V



### **Input Pin Function**

### (1) Chip enable function

This IC is switched between standby and operating mode by setting the ST pin. In standby mode, the IC is set to power-save mode and all logic is reset. In addition, the internal regulator circuit and charge pump circuit do not operate in standby mode.

ST	Mode	Internal regulator	Charge pump
Low or Open	Standby mode	Standby	Standby
High	Operating mode	Operating	Operating

### (2) Drive mode switching pin function

The IC drive mode is switched by setting the DM pin. In STM mode, stepping motor channel 1 can be controlled by the CLK-IN input. In DCM mode, DC motor channel 2 or stepping motor channel 1 can be controlled by parallel input. Stepping motor control using parallel input is 2-phase or 1-2 phase full torque.

DM	Drive mode	Application
Low or Open	STM mode	Stepping motor channel 1 (CLK-IN)
High	DCM mode	DC motor channel 2 or stepping motor channel 1 (parallel)

### STM mode (DM = Low or Open)

### (1) STEP pin function

Input		Operating mode
ST	STP	
Low	*	Standby mode
High		Excitation step proceeds
High		Excitation step is kept

### (2) Excitation mode setting function

MD1	MD2	Excitation mode	Initial position	
			Channel 1	Channel 2
Low	Low	2 phase excitation	100%	-100%
High	Low	1-2 phase excitation (full torque)	100%	0%
Low	High	1-2 phase excitation	100%	0%
High	High	W1-2 phase excitation	100%	0%

This is the initial position of each excitation mode in the initial state after power-on and when the counter is reset.

#### (3) Constant-current control reference voltage setting function

ATT1	ATT2	Current setting reference voltage
Low	Low	VREF/3×100%
High	Low	VREF/3×67%
Low	High	VREF/3×50%
High	High	VREF/3×33%

The voltage input to the VREF pin can be switched to four-step settings as the reference voltage for setting the output current. This is effective for reducing power consumption when motor holding current is supplied.

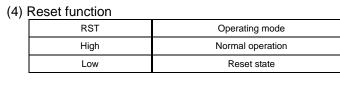
### Set current value calculation method

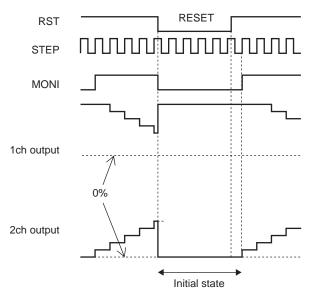
The reference voltage is set by the voltage applied to the VREF pin and the two inputs ATT1 and ATT2. The output current (output current at a constant-current drive current ratio of 100%) can be set from this reference voltage and the RF resistance value.

 $I_{OUT} = (VREF/3 \times Voltage setting ratio)/RF resistor$ 

(Example) When VREF = 1.5V, setting current ratio = 100% [(ATT1, ATT2) = (Low, Low)] and RF resistor =  $0.5\Omega$ , the following output current flows :

 $I_{OUT} = 1.5V/3 \times 100\%/0.5\Omega = 1A$ 



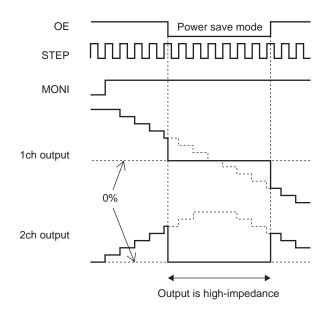


When the RST pin is set Low, the output excitation position is forced to the initial state, and the MONI output also goes Low.

When RST is set High after that, the excitation position proceeds to the next STEP input.

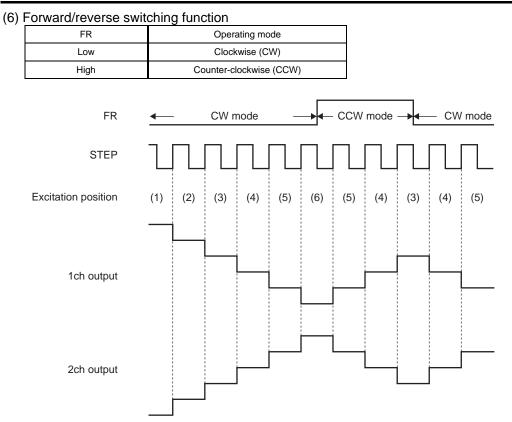
(5) Output enable function

OE	Operating mode
Low	Output OFF
High	Output ON



When the OE pin is set Low, the output is forced OFF and goes to high impedance.

However, the internal logic circuits are operating, so the excitation position proceeds when the STEP signal is input. Therefore, when OE is returned to High, the output level conforms to the excitation position proceeded by the STEP input.

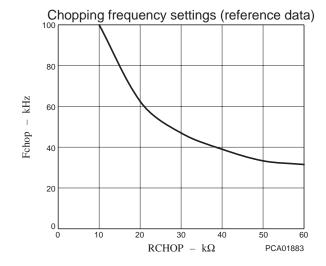


The internal D/A converter proceeds by one bit at the rising edge of the input STEP pulse. In addition, CW and CCW mode are switched by setting the FR pin. In CW mode, the channel 2 current phase is delayed by  $90^{\circ}$  relative to the channel 1 current. In CCW mode, the channel 2 current phase is advanced by  $90^{\circ}$  relative to the channel 1 current.

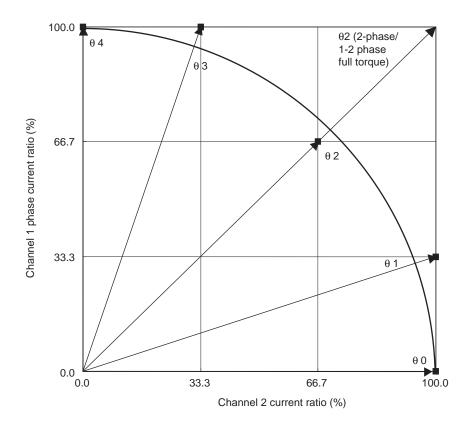
### (7) Setting the chopping frequency

For constant-current control, chopping operation is made with the frequency determined by the external resistor (connected to the RCHOP pin).

The chopping frequency to be set with the resistance connected to the RCHOP pin (pin 11) is as shown below.



### (8) Output current vector locus (one step is normalized to 90 degrees)

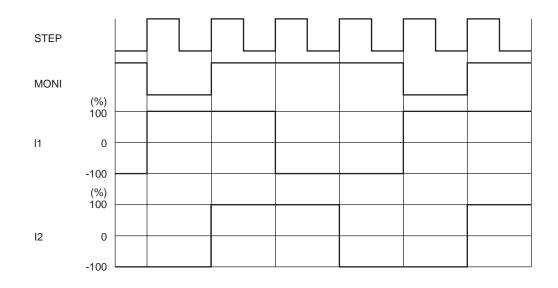


Setting cur	rrent ration	in each	excitation	mode
Setting ea	rom ranon	i iii cacii	enertation	moue

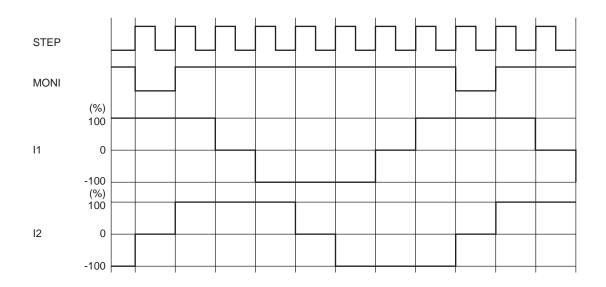
STEP	W1-2 ph	ase (%)	1-2 pha	ase (%)	1-2 phase fu	ll torque (%)	2-phas	e (%)
	Channel 1	Channel 2	Channel 1	Channel 2	Channel 1	Channel 2	Channel 1	Channel 2
θ0	0	100	0	100	0	100		
θ1	33.3	100						
θ2	66.7	66.7	66.7	66.7	100	100	100	100
θ3	100	33.3						
θ4	100	0	100	0	100	0		

### (9) Typical current waveform in each excitation mode

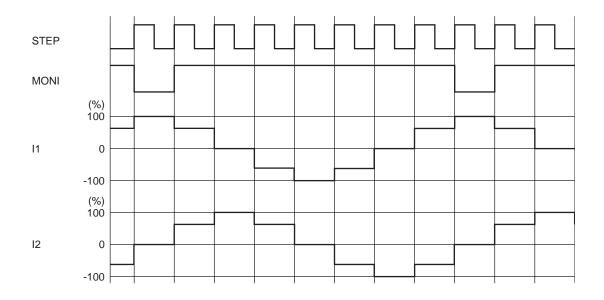
2-phase excitation (CW mode)



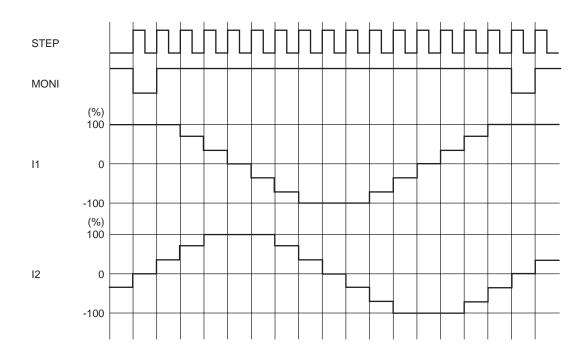
### 1-2 phase excitation full torque (CW mode)



1-2 phase excitation (CW mode)

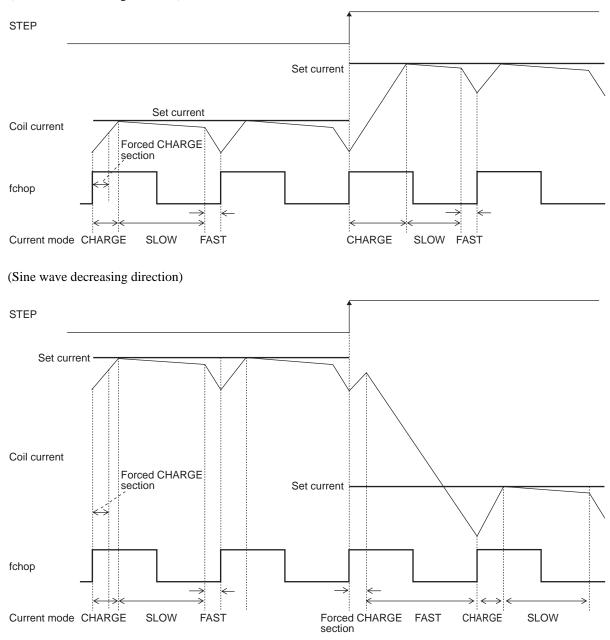


W1-2 phase excitation (CW mode)



### (10) Current control operation specification

(Sine wave increasing direction)



In each current mode, the operation sequence is as described below :

- At rise of chopping frequency, the CHARGE mode begins. (The section in which the CHARGE mode is forced regardless of the magnitude of the coil current (ICOIL) and set current (IREF) exists for 1/16 of one chopping cycle.)
- The coil current (ICOIL) and set current (IREF) are compared in this forced CHARGE section.
  - When (ICOIL<IREF) state exists in the forced CHARGE section;

CHARGE mode up to ICOIL  $\geq$  IREF, then followed by changeover to the SLOW DECAY mode, and finally by the FAST DECAY mode for the 1/16 portion of one chopping cycle.

When (ICOIL<IREF) state does not exist in the forced CHARGE section;

The FAST DECAY mode begins. The coil current is attenuated in the FAST DECAY mode till one cycle of chopping is over.

Above operations are repeated. Normally, the SLOW (+FAST) DECAY mode continues in the sine wave increasing direction, then entering the FAST DECAY mode till the current is attenuated to the set level and followed by the SLOW DECAY mode.

### DCM Mode (DM-High)

### (1) DCM mode output control logic

Parallel input		Output		Mode
DC11 (21)	DC12 (22)	OUT1 (2) A	OUT1 (2) B	
Low	Low	OFF	OFF	Standby
High	Low	High	Low	CW (Forward)
Low	High	Low	High	CCW (Reverse)
High	High	Low	Low	Brake

### (2) Reset function

RST	Operating mode	MONI
High or Low	Reset operation not performed	High output

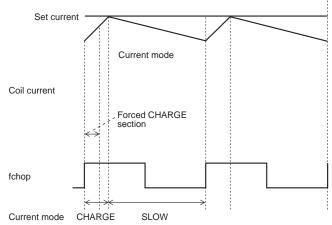
The reset function does not operate in DCM mode. In addition, the MONI output is High, regardless of the RST pin state.

### (3) Output enable function

OE	Operating mode
Low	Output OFF
High	Output ON

When the OE pin is set Low, the output is forced OFF and goes to high impedance. When the OE pin is set High, output conforms to the control logic.

### (4) Current limit control time chart



### (5) Current limit reference voltage setting function

ATT1	ATT2	Current setting reference voltage
Low	Low	VREF/3×100%
High	Low	VREF/3×67%
Low	High	VREF/3×50%
High	High	VREF/3×33%

The voltage input to the VREF pin can be switched to four-step settings as the reference voltage for setting the current limit.

### Set current calculation method

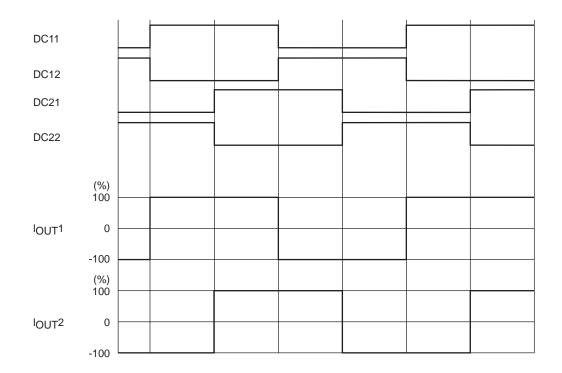
The reference voltage is set by the voltage applied to the VREF pin and the two inputs ATT1 and ATT2. The current limit can be set from this reference voltage and the RF resistance value.

Ilimit =  $(VREF/3 \times Voltage setting ratio) / RF resistance$ 

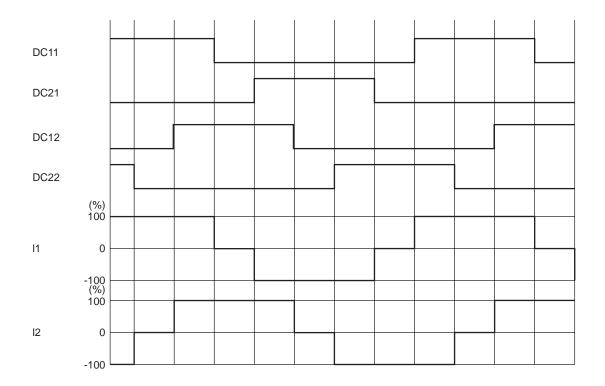
(Example) When VREF = 1.5V, setting current ratio = 100% [(ATT1, ATT2) = (Low, Low)] and RNF1 (2) =  $0.5\Omega$ , the current limit value is as follows :

Ilimit =  $1.5V/3 \times 100\%/0.5\Omega = 1A$ 

# (6) Typical current waveform in each excitation mode when stepping motor parallel input control 2-phase excitation (CW mode)



1-2 phase excitation full torque (CW mode)



### **Output short-circuit protection circuit**

To protect IC from damage due to short-circuit of the output caused by lightening or ground fault, the output short-circuit protection circuit to put the output in the standby mode is incorporated.

(1) Output short-circuit protection operation changeover function

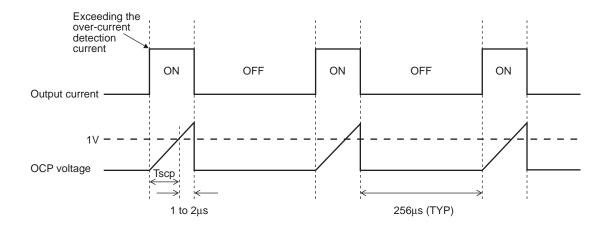
Changeover to the output short-circuit protection of IC is made by the setting of OCPM pin.

EMM	State
Low or Open	Auto reset method
High	Latch method

### (2) Auto reset method

When the output current is below the output short-circuit protection current, the output is controlled by the input signal. When the output current exceeds the detection current, the switching waveform as shown below appears instead.

(When the resistor inserted between RCHOP-GND is  $20k\Omega$ )



When detecting the output short-circuit state, the short-circuit detection circuit is activated. When the short-circuit detection circuit operation exceeds the timer latch time described later, the output is changed over to the standby mode and reset to the ON mode again in 256µs (TYP). In this event, if the overcurrent mode still continues, the above switching mode is repeated till the overcurrent mode is canceled.

(3) Latch method

Similarly to the case of automatic reset method, the short-circuit detection circuit is activated when it detects the output short-circuit state.

When the short-circuit detection circuit operation exceeds the timer latch time described later, the output is changed over to the standby mode.

In this method, latch is released by setting PS = "L"

(4) Output short-circuit condition warning output pin

EMO, warning output pin of the output short-circuit protection circuit, is an open-drain output. EMO outputs ON when output short-circuit is detected.

### (5) Timer latch time (Tscp)

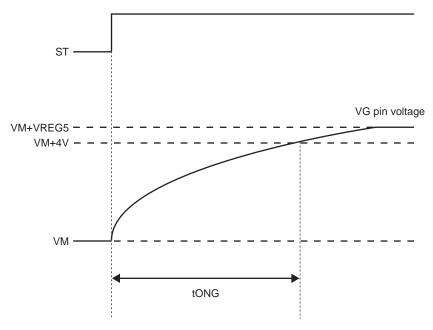
The time to output OFF when an output short-circuit occurs can be set by the capacitor connected between the CEM pin and GND. The capacitor (C) value can be determined as follows :

Timer latch : Tscp	$Tscp \approx Td+C \times V/I [sec]$
	Td : Internal delay time TYP 4µs
	V : Threshold voltage of comparator TYP 1V
	I : CEM charge current TYP 2.5µA

The Tscp time must be set so as not to exceed 80% of the chopping period. The CEN pin must be connected to (S) GND when the output short protection function is not to be used.

### **Charge Pump Circuit**

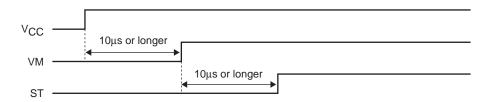
When the ST pin is set High, the charge pump circuit operates and the VG pin voltage is boosted from the VM voltage to the VM + VREG5 voltage. If the VG pin voltage is not boosted sufficiently, the output cannot be controlled, so be sure to provide a wait time of tONG or more after setting the ST pin High before starting to drive the motor.



VG Pin Voltage Schematic View

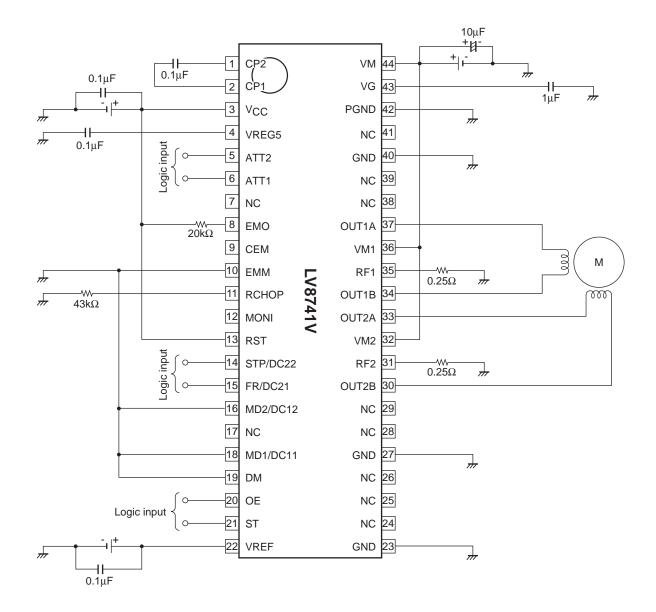
### **Recommended Power-on Sequence**

Provide a wait time of  $10\mu$ s or more after the V<sub>CC</sub> power supply rises before supplying the motor power supply. Provide a wait time of  $10\mu$ s or more after the motor power supply rises before setting the ST pin High.



### **Application Circuits**

• Stepping motor driver application circuit example



The setting conditions for the above circuit diagram example are as follows :

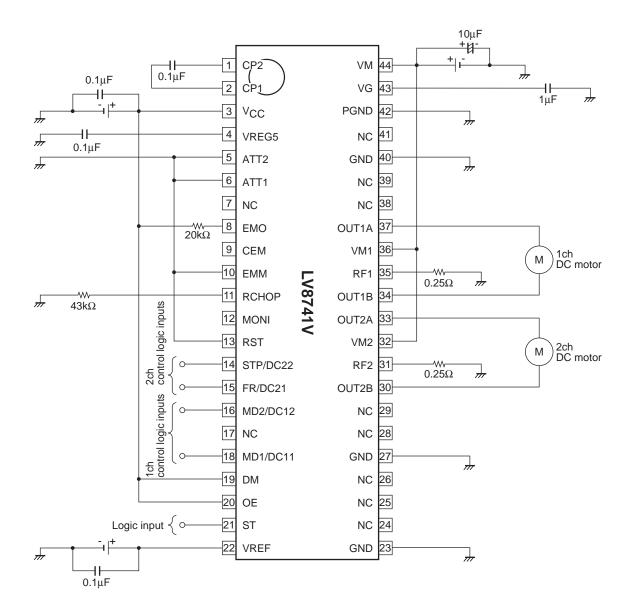
- 2-phase excitation (MD1/DC11 = Low, MD2/DS12 = Low)
- Auto recovery-type output short-circuit protection function (EMM = Low)
- Reset function fixed to normal operation (RST = High)
- Output enable function fixed to output ON state (OE = High)

ATT1	ATT2	Current setting reference voltage
L	L	VREF/3×100%
Н	L	VREF/3×67%
L	Н	VREF/3×50%
Н	Н	VREF/3×33%

The set current value is as follows :

 $I_{OUT} = (VREF/3 \times Voltage setting ratio) /0.25\Omega$ 

• DC motor driver application circuit example



The setting conditions for the above circuit diagram example are as follows :

- Auto recovery-type output short-circuit protection function (EMM = Low)
- Output enable function fixed to output ON state (OE = High)
- Current limit reference voltage setting = 100% (ATT1 = Low, ATT2 = Low)

The current limit value is as follows :  $Ilimit = (VREF/3) / 0.25\Omega$ 

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